

SEMICONDUCTOR®

## November 2013

# FQPF2N80

## **N-Channel QFET<sup>®</sup> MOSFET** 800 V, 1.5 A, 6.3 Ω

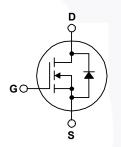
## Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

## Features

- 1.5 A, 800 V,  $\rm R_{DS(on)}$  = 6.3  $\Omega$  (Max.) @ V\_{GS} = 10 V,  $\rm I_{D}$  = 0.75 A
- Low Gate Charge (Typ. 12 nC)
- Low Crss (Typ. 5.5 pF)
- 100% Avalanche Tested





## Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

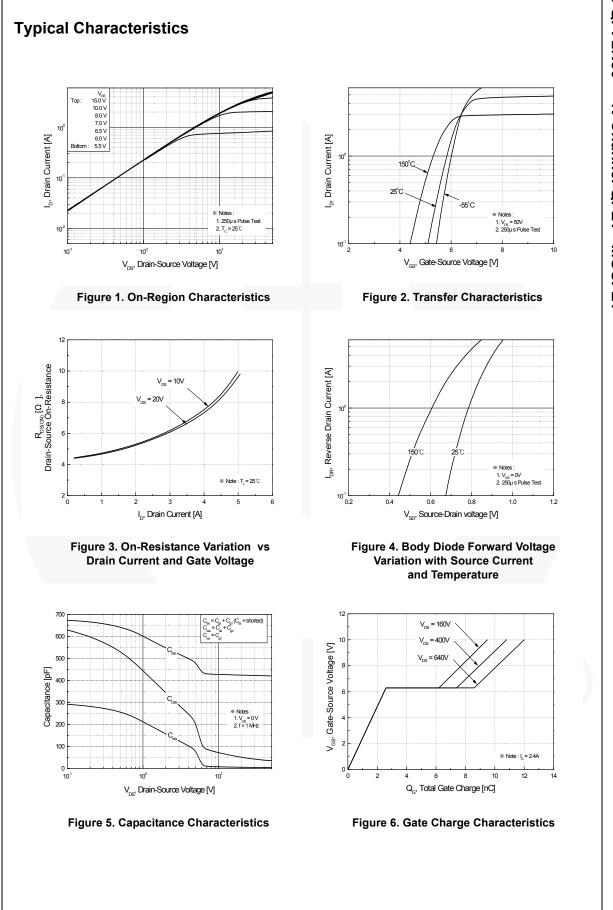
Symbol	Parameter		FQPF2N80	Unit
V <sub>DSS</sub>	Drain-Source Voltage		800	V
I <sub>D</sub>	Drain Current - Continuous (T <sub>C</sub> = 25°	C)	1.5	A
	- Continuous (T <sub>C</sub> = 100	°C)	0.95	A
I <sub>DM</sub>	Drain Current - Pulsed	(Note 1)	6.0	A
V <sub>GSS</sub>	Gate-Source Voltage		± 30	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy	(Note 2)	180	mJ
I <sub>AR</sub>	Avalanche Current	(Note 1)	1.5	А
E <sub>AR</sub>	Repetitive Avalanche Energy	(Note 1)	3.5	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	4.0	V/ns
P <sub>D</sub>	Power Dissipation (T <sub>C</sub> = 25°C)		35	W
	- Derate above 25°C		0.28	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +150	°C
Τ <sub>L</sub>	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 seconds		300	°C

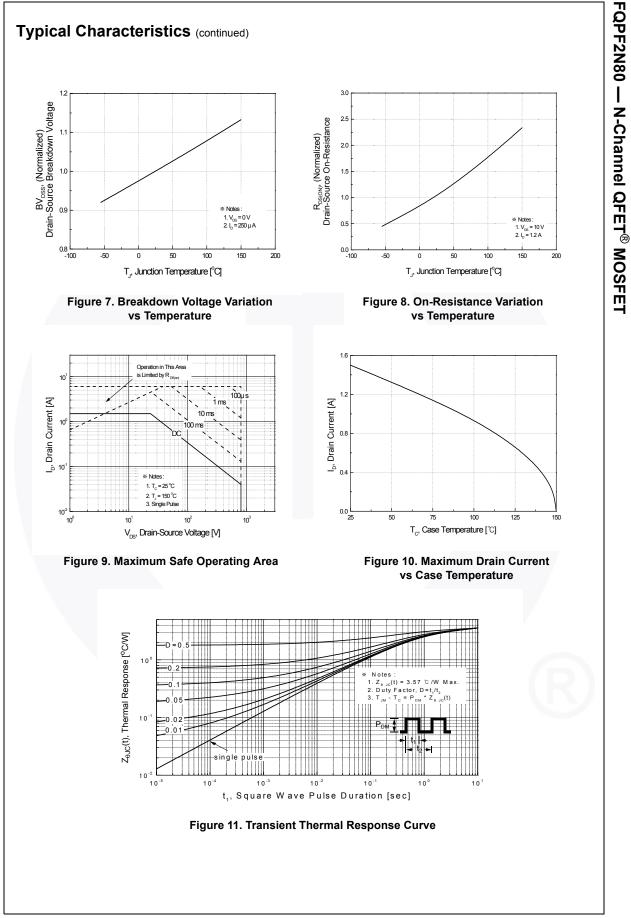
## **Thermal Characteristics**

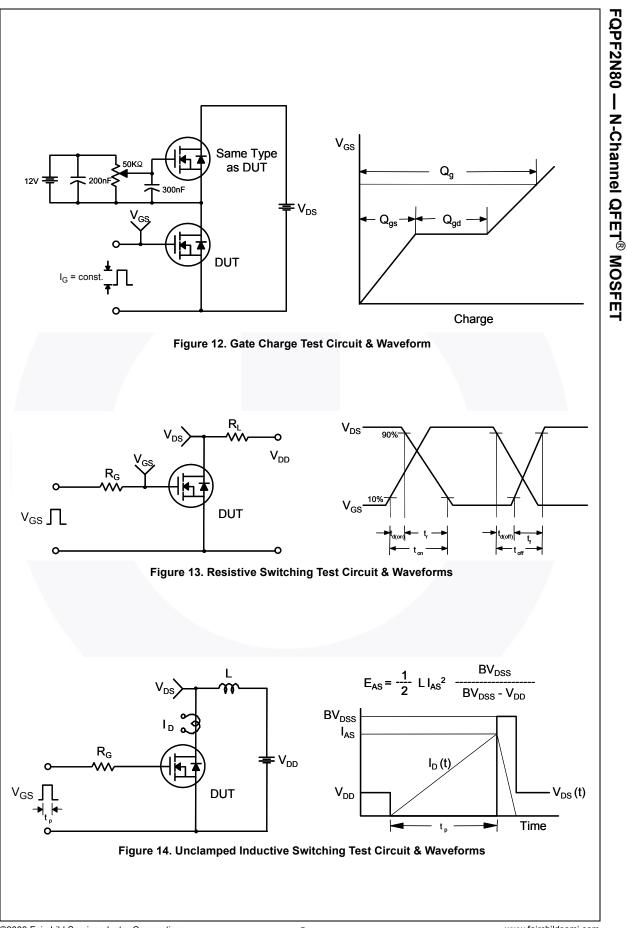
Symbol	Parameter	FQPF2N80	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	3.57	°C/W	
$R_{ hetaJA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W	

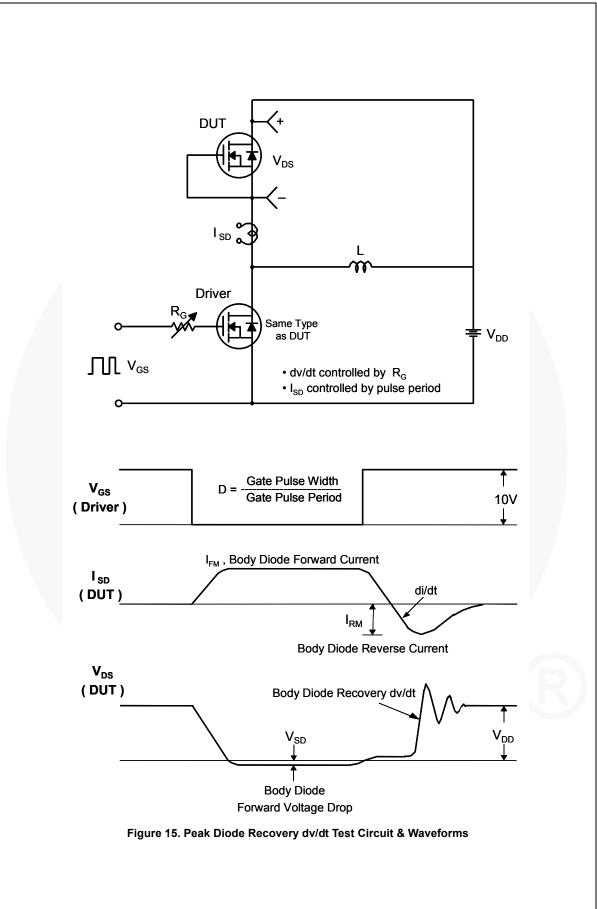
Part NumberTop MarkPackageFQPF2N80FQPF2N80TO-220F		Package	e Packing Method Re	Reel Size	Tape Width		th Q	Quantity	
		Tube N/A		N/A		5	50 units		
lectri	cal C	haracteristics	T <sub>C</sub> = 25°C	unless otherwise noted.					
Symbol		Parameter		Test Condit	ions	Min	Тур	Max	Unit
Off Cha	aracte	ristics							
BV <sub>DSS</sub>	Drain-	Source Breakdown V	oltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA		800			V
∆BV <sub>DSS</sub> ∆T,I	Breakdown Voltage Temperature Coefficient		rature	$I_D = 250 \ \mu\text{A}$ , Referenced to 25°C			0.9		V/°C
DSS				V <sub>DS</sub> = 800 V, V <sub>GS</sub> = 0	0 V			10	μA
	Zero (	Gate Voltage Drain Co	urrent	$V_{DS} = 640 \text{ V}, \text{ T}_{C} = 12$	25°C			100	μΑ
GSSF	Gate-I	Body Leakage Currer	nt, Forward	V <sub>GS</sub> = 30 V, V <sub>DS</sub> = 0 V				100	nA
GSSR	Gate-I	Body Leakage Currer	nt, Reverse	$V_{GS}$ = -30 V, $V_{DS}$ = 0	) V			-100	nA
On Cha	racter	ristics							
/ <sub>GS(th)</sub>	1	Threshold Voltage		$V_{DS} = V_{GS}, I_{D} = 250$	μA	3.0		5.0	V
R <sub>DS(on)</sub>	Static	Drain-Source		V <sub>GS</sub> =10V, I <sub>D</sub> =0.75A			4.9	6.3	Ω
FS	Forward Transconductance			V <sub>DS</sub> = 50 V, I <sub>D</sub> = 0.75 A			2.2		S
-	1	racteristics							_
Piss		Capacitance		$V_{DS}$ = 25 V, $V_{GS}$ = 0	V,		425	550	pF
Soss		t Capacitance		f = 1.0 MHz			45	60	pF
rss	Rever	se Transfer Capacita	nce				5.5	7.0	pF
Switch	ing Ch	aracteristics							
d(on)	Turn-0	On Delay Time		V <sub>DD</sub> = 400 V, I <sub>D</sub> = 2.4	4 A.		12	35	ns
•	Turn-0	On Rise Time		$R_{G} = 25 \Omega$	,		30	70	ns
d(off)	Turn-0	Off Delay Time		0	<b></b>		25	60	ns
	Turn-0	Off Fall Time			(Note 4)		28	65	ns
ζ <sub>g</sub>	Total C	Gate Charge		V <sub>DS</sub> = 640 V, I <sub>D</sub> = 2.4	1 A,		12	15	nC
ک <sub>gs</sub>	Gate-S	Source Charge		V <sub>GS</sub> = 10 V			2.6		nC
۵ <sub>gd</sub>	Gate-I	Drain Charge			(Note 4)		6.0		nC
Drain-S	ource	Diode Characte	eristics an	d Maximum Rati	ings				
S		num Continuous Drai			-			1.5	Α
SM	Maxim	num Pulsed Drain-So	urce Diode F					6.0	Α
/ <sub>SD</sub>	Drain-	Source Diode Forwa	d Voltage	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 1.5 A			-	1.4	V
т		se Recovery Time	Ŭ	$V_{GS} = 0 V, I_S = 2.4 A$			480		ns
۰. ک <sup>رر</sup>		se Recovery Charge		dl <sub>F</sub> / dt = 100 A/µs			2.0		μC
	1	, ,						1	

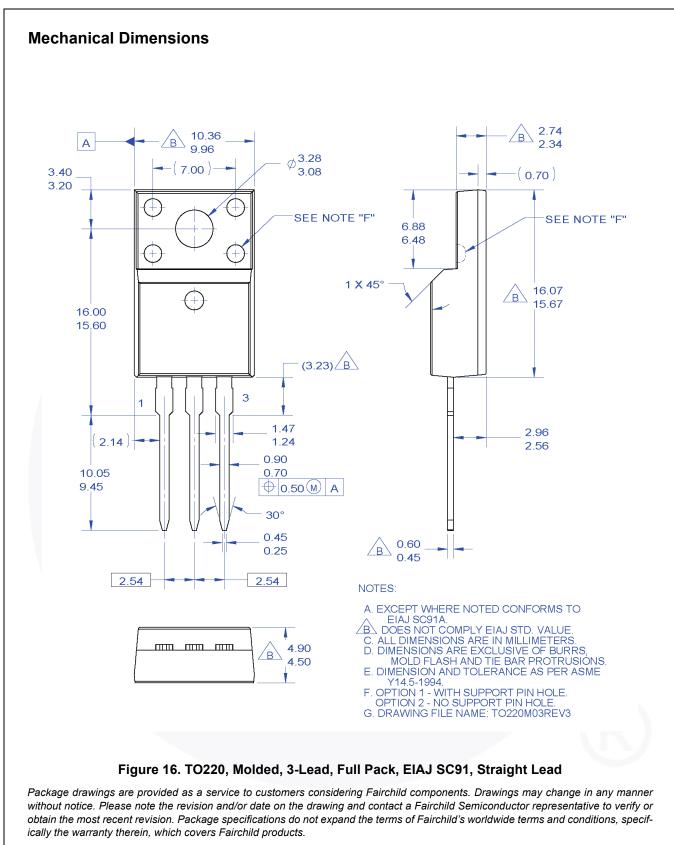
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